

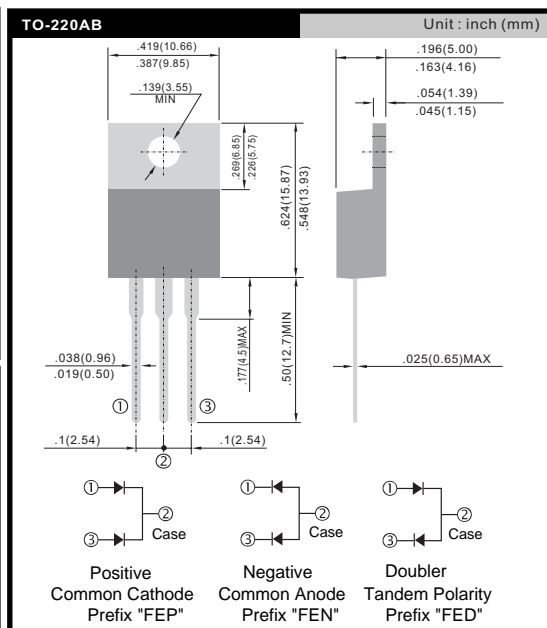


## FEP16DT thru FEP6JT

**Pb Free Plating Product**

16.0 Ampere Dual Fast Efficient Positive Polarity Half Bridge Rectifiers

<p><b>Features</b></p> <ul style="list-style-type: none"> <li>★ Super fast switching for high efficiency</li> <li>★ Low forward voltage drop</li> <li>★ High current capability</li> <li>★ Low reverse leakage current</li> <li>★ High surge current capability</li> </ul> <p><b>Application</b></p> <ul style="list-style-type: none"> <li>★ Automotive Inverters/Solar Inverters</li> <li>★ Plating Power Supply, Adaptor, SMPS and UPS</li> <li>★ Car Audio Amplifiers and Sound Device Systems</li> </ul>
<p><b>Mechanical Data</b></p> <ul style="list-style-type: none"> <li>★ Case: TO-220AB Heatsink</li> <li>★ Epoxy: UL 94V-0 rate flame retardant</li> <li>★ Terminals: Solderable per MIL-STD-202 method 208</li> <li>★ Polarity: As marked on diode body</li> <li>★ Mounting position: Any</li> <li>★ Weight: 2.2 gram approximately</li> </ul>



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOL	FEP16DT	FEP16GT	FEP16JT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=100°C	IF(AV)	16.0			A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	175	150		A
Maximum Instantaneous Forward Voltage @ 8.0 A	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @Tj=25°C At Rated DC Blocking Voltage @Tj=125°C	IR		10.0		uA
			250		uA
Maximum Reverse Recovery Time (Note 1)	Trr		35		nS
Typical junction Capacitance (Note 2)	CJ		90		pF
Typical Thermal Resistance (Note 3)	RθJC		2.2		°CW
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to + 150			°C

NOTES : (1) Reverse recovery test conditions IF = 0.5A, R = 1.0A, Irr = 0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

(3) Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

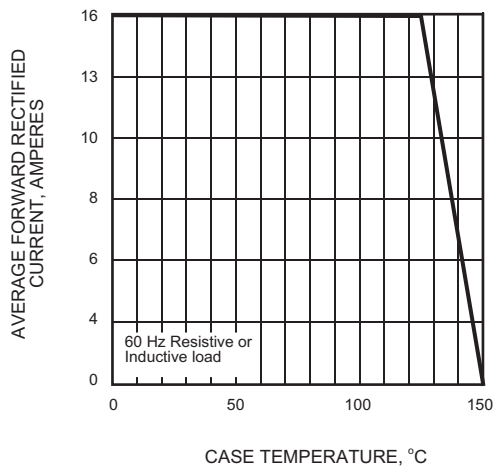


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

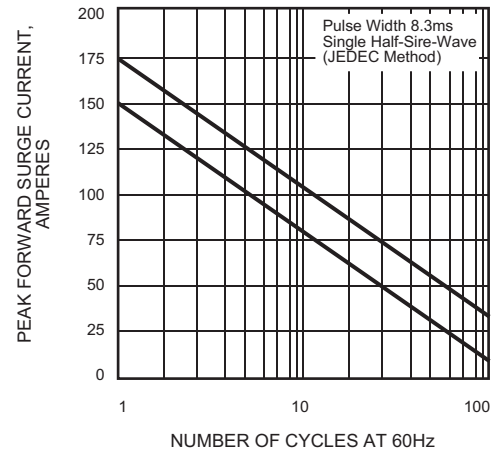


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

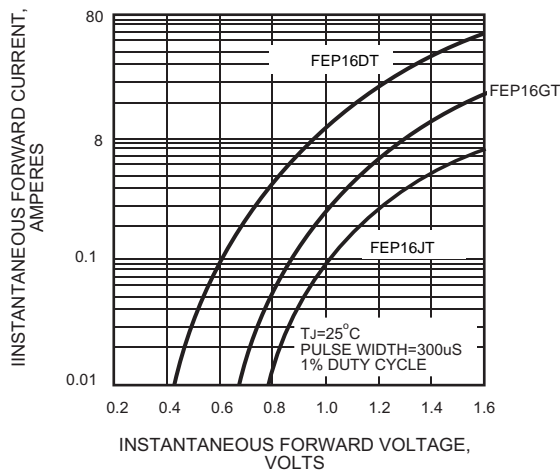


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

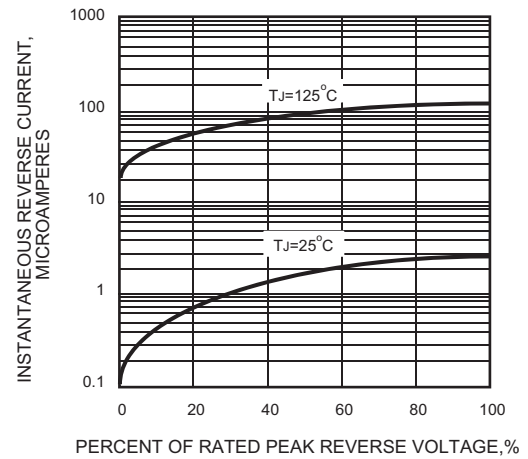


FIG.5 - TYPICAL JUNCTION CAPACITANCE

